

Product Summary

BV _{DSS}	R _{DS(ON)} Max	Ι _D T _C = +25°C
60V	5.6mΩ @ V _{GS} = 10V	90A

Description and Applications

This MOSFET has been designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Engine management systems
- Body control electronics
- DC-DC converters

Features

- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching Ensures More Reliable and Robust End Application
- Low R_{DS(ON)} Minimizes Power Losses
- Low Qg Minimizes Switching Losses
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DIODES™ DMTH6005LK3Q is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

Mechanical Data

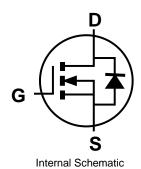
- Package: TO252
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.33 grams (Approximate)



Top View Pin Out

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Ordering Information (Note 4)

Part Number	Backaga	Packing		
Fait Nulliper	Package	Qty.	Carrier	
DMTH6005LK3Q-13	TO252 (DPAK)	2,500	Tape & Reel	

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Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



DII = Manufacturer's Marking H6005L = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 22 = 2022) WW = Week Code (01 to 53)



Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units		
Drain-Source Voltage	Vdss	60	V		
Gate-Source Voltage	V _{GSS}	±20	V		
Continuous Drain Current (Note 6)	T _C = +25°C (Note 9)	lo	90	А	
	Tc = +100°C		70	1	
Maximum Body Diode Forward Current (Note 6)	Tc = +25°C	ls	90	A	
Pulsed Drain Current (10µs pulse, duty cycle = 1%)	Idм	150	A		
Avalanche Current, L=1mH	las	14.8	A		
Avalanche Energy, L=1mH	E _{AS}	98	mJ		

Thermal Characteristics

Characteristic		Symbol	Value	Units
Total Power Dissipation (Note 5)	T _A = +25°C	PD	3.9	W
Thermal Resistance, Junction to Ambient (Note 5)		Reja	38	°C/W
Total Power Dissipation (Note 6)	Tc = +25°C	PD	100	W
Thermal Resistance, Junction to Case (Note 6)		R _{0JC}	1.5	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BV _{DSS}	60	_	_	V	$V_{GS} = 0V, I_D = 1mA$
Zero Gate Voltage Drain Current	IDSS	_	_	1	μA	V _{DS} = 48V, V _{GS} = 0V
Gate-Source Leakage	Igss		_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	Vgs(th)	1	—	3	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$
		_	4.5	5.6		Vgs = 10V, ID = 50A
Static Drain-Source On-Resistance	RDS(ON)		5.6	7.2	mΩ	Vgs = 6V, ID = 20A
			7.9	10		V _{GS} = 4.5V, I _D = 12.5A
Diode Forward Voltage	Vsd		_	1.2	V	V _{GS} = 0V, I _S = 20A
DYNAMIC CHARACTERISTICS (Note 8)				•		
Input Capacitance	Ciss	_	2962	_		$V_{DS} = 30V, V_{GS} = 0V,$ f = 1MHz
Output Capacitance	Coss	_	965.2	_	pF	
Reverse Transfer Capacitance	Crss	_	59.8	_		
Gate Resistance	Rg	_	0.66	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge (V _{GS} = 10V)	Qg	_	47.1	_		
Total Gate Charge (V _{GS} = 4.5V)	Qg		23.1	_	-0	
Gate-Source Charge	Qgs		10.2	_	nC	$V_{DD} = 30V, I_D = 50A$
Gate-Drain Charge	Q _{gd}		12.5	—		
Turn-On Delay Time	tD(ON)	_	8.3	_		
Turn-On Rise Time	tR		9.4			$V_{DD} = 30V, V_{GS} = 10V,$
Turn-Off Delay Time	tD(OFF)	_	22	_	ns	$I_D = 30A, R_G = 3.3\Omega$
Turn-Off Fall Time	tF		8.9	—	1	
Body Diode Reverse Recovery Time	t _{RR}		40.4	—	ns	
Body Diode Reverse Recovery Charge	Q _{RR}	_	49.7	_	nC	Ιϝ = 30A, di/dt = 100A/μs

5. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper pad layout. Notes:

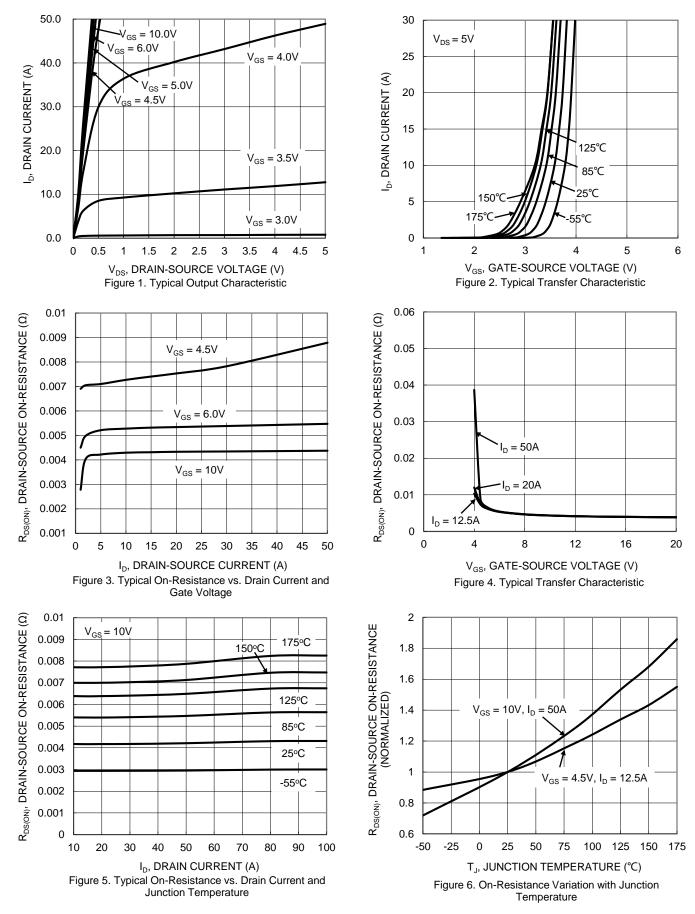
6. Thermal resistance from junction to soldering point (on the exposed drain pad).7. Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to production testing.

9. Package limited.



DMTH6005LK3Q



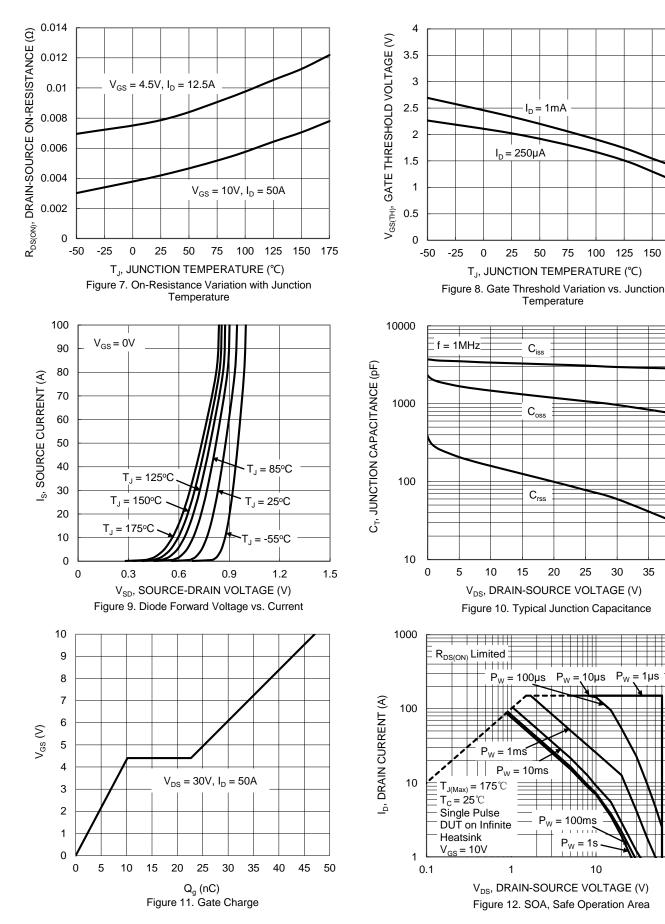
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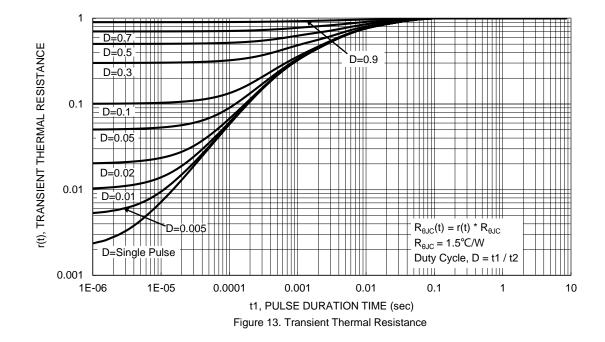
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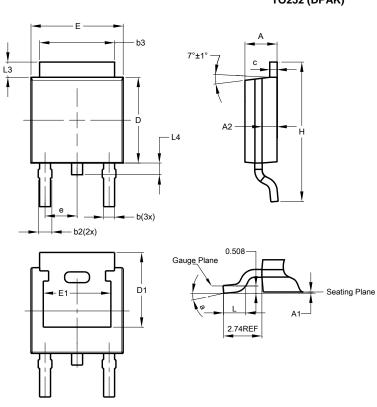






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

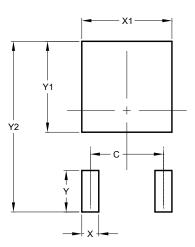


TO252 (DPAK)					
Dim	Min	Max	́ Тур		
Α	2.19	2.39	2.29		
A1	0.00	0.13	0.08		
A2	0.97	1.17	1.07		
b	0.64	0.88	0.783		
b2	0.76	1.14	0.95		
b3	5.21	5.50	5.33		
С	0.45	0.58	0.531		
D	6.00	6.20	6.10		
D1	5.21	-			
е	2.286 BSC				
Ε	6.45	6.70	6.58		
E1	4.32				
Н	9.40	10.41	9.91		
L	1.40	1.78	1.59		
L3	0.88	1.27	1.08		
L4	0.64	1.02	0.83		
а	0°	10°			
All	All Dimensions in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

TO252 (DPAK)



Dimensions	Value (in mm)
С	4.572
Х	1.060
X1	5.632
Y	2.600
Y1	5.700
Y2	10.700

TO252 (DPAK)



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